# NSN 5962-01-299-6854

Memory Microcircuit - Page 1 of 1



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## **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

## Features Provided:

Hermetically sealed and programmed

## Inclosure Material:

Ceramic

## Inclosure Configuration:

Dual-in-line

### **Output Logic Form:**

Transistor-transistor logic

## Case Outline Source And Designator:

D-2 mil-m-38510

**Terminal Surface Treatment:** 

Solder

#### Voltage Rating And Type Per Characteristic:

7.0 volts power source

#### **Time Rating Per Chacteristic:**

80.00 nanoseconds delay

#### Memory Device Type:

Rom

#### Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

#### Terminal Type And Quantity:

16 printed circuit

#### Shelf Life:

N/a

#### Unit Of Measure:

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# Demilitarization:

Yes - demil/mli

#### Fiig:

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